New Product

SS2P2L & SS2P3L

Vishay General Semiconductor

Low V_F High Current Density Surface Mount Schottky Barrier Rectifiers

eSMP[™] Series



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V _{RRM}	20 V, 30 V				
I _{FSM}	50 A				
E _{AS}	11.25 mJ				
V _F	0.45 V				
T _J max.	150 °C				

FEATURES

- · Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
 - Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheelling, dc-to-dc converters, and polarity protection applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS2P2L	SS2P3L	UNIT	
Device marking code		22L	23L		
Maximum repetive peak reverse voltage	V _{RRM} 20 30			V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.0		A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50		A	
Non-repetitive avalanche energy at I_{AS} = 1.5 A, L = 10 mH, T_{J} = 25 $^{\circ}\text{C}$	E _{AS}	11.25		mJ	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/us	
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150		°C	

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 2 A I _F = 2 A	T _J = 25 °C T _J = 125 °C	V _F	0.45 0.38	0.50 0.45	V
Maximum reverse current at rated $V_R^{(2)}$		T _J = 25 °C T _J = 125 °C	I _R	- 9.0	200 20	μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	130		pF

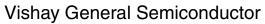
Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle (2) Pulse test: Pulse width \leq 40 ms

 Document Number: 88916
 For technical questions within your region, please contact one of the following:

 Revision: 19-May-08
 PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com







THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	SS2P2L	SS2P3L	UNIT
Typical thermal resistance ⁽¹⁾	${f R}_{ heta JA} \ {f R}_{ heta JL} \ {f R}_{ heta JC}$	115 15 20		°C/W

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS2P3L-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS2P3L-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
SS2P3LHE3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel		
SS2P3LHE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

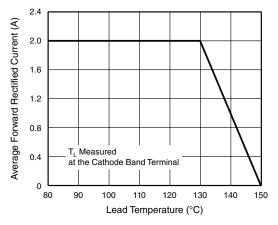


Figure 1. Forward Current Derating Curve

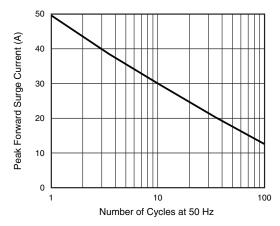


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



SS2P2L & SS2P3L

Vishay General Semiconductor

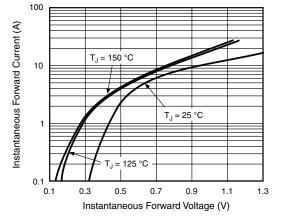


Figure 3. Typical Instantaneous Forward Characteristics

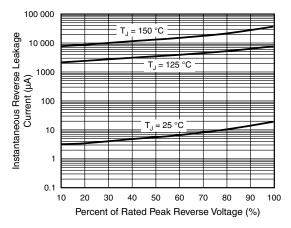


Figure 4. Typical Reverse Leakage Characteristics

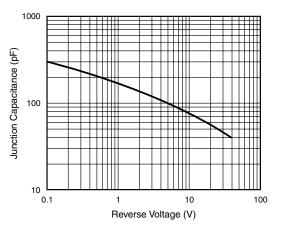


Figure 5. Typical Junction Capacitance

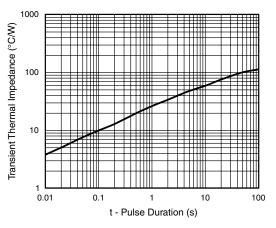
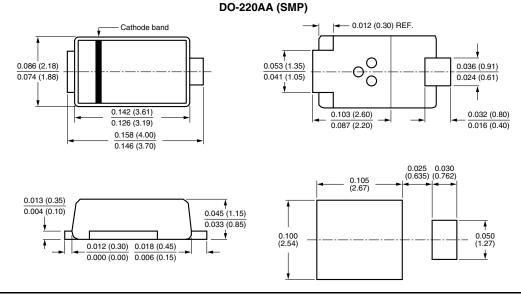


Figure 6. Typical Transient Thermal impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Document Number: 88916 Revision: 19-May-08 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.